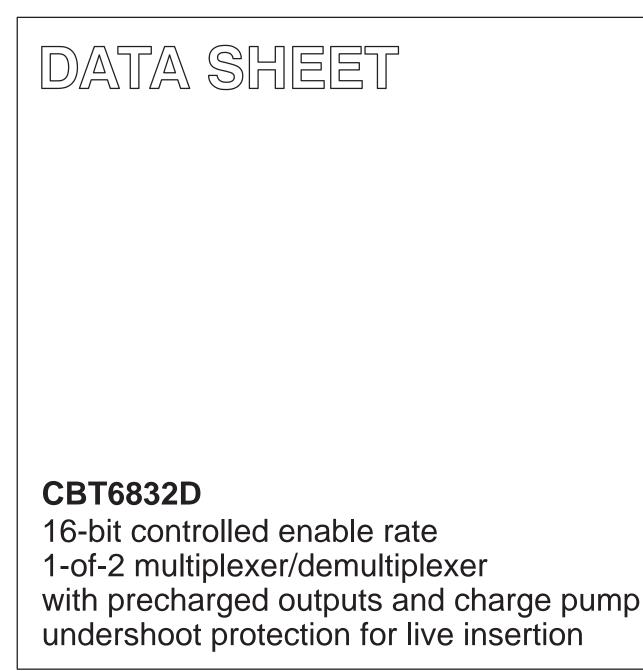
INTEGRATED CIRCUITS



Preliminary specification

2000 May 18



CBT6832D

SW00478

FEATURES	PIN CONFIGURATION	
• 5 Ω typical r _{on}		_
 Pull-up on B port 	1B1 1	56 1A
 Undershoot protection on A port only: –2.0 V 	2B1 2	55 1B2
Near zero propagation delay	2A 3	54 2B2
Controlled enable rate	3B1 4	53 3A
• V_{CC} operating range: +4.5 V to +5.5 V	4B1 5 4A 6	52 3B2 51 4B2
	5B1 7	50 5A
 > 100 MHz bandwidth (or clock rate) at 20 pF load capacitance 	6B1 8	49 5B2
 56-pin TSSOP package 	e A 6	48 6B2
 Bias voltage pre-charges the B output when the channel is 	7B1 10	47 7A
disabled	8B1 11	46 7B2
 Latch-up protection exceeds 100 mA per JESD78 	8A 12	45 8B2
 ESD protection exceeds 2000 V HBM per JESD22-A114, 200 V MM per JESD22-A115 and 1000 V CDM per JESD22-C101 	GND 13	44 GND
200 V Mini per JESD22-ATTS and 1000 V CDM per JESD22-CT01	V _{CC} 14	43 V _{CC}
	9B1 15	42 9A
APPLICATION	10B1 16	41 9B2
 Provides PCI-X hot-plugging 	10A 17	40 10B2
	11B1 [18	39 11A
DESCRIPTION	12B1 [19	38 11B2
The CBT6832D is a 16-bit controlled enable rate 1-of-2	12A 20	37 12B2
multiplexer/demultiplexer with precharged outputs and charge pump undershoot protection for live insertion. Advantages of the CBT6832	13B1 21 14B1 22	36 13A 35 13B2
include a propagation delay of 250 ps, resulting from 5 Ω channel	14B1 22 14A 23	33 13B2 34 14B2
resistance, and low I/O capacitance. A port demultiplexes to either	15B1 [24	33 15A
1B and 2B, or to both. The switch is bi-directional.	16B1 [25	32 15B2
	16A 26	31 16B2
	V _{BIAS1} 27	30 V _{BIAS2}
	SEL1 [28	29 SEL2

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0 V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	$C_{L} = 50 \text{ pF}; V_{CC} = 5 \text{ V}$	0.25	ns
C _{IN}	Input capacitance	$V_{I} = 0 V \text{ or } V_{CC}$	4.5	pF
C _{OFF B}	B capacitance, switch off	Outputs disabled; $V_0 = 0 V$	8	pF
C _{OFF A}	A capacitance, switch off	Outputs disabled; $V_0 = 0 V$	13	pF
C _{ON 1}	One channel enabled capacitance	One B enabled; $V_0 = 0 V$	21	pF
C _{ON 2}	Both channels enabled capacitance	Both B channels enabled; $V_0 = 0 V$	34	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 5.5 V$		μA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
56-Pin Plastic TSSOP Type II	–40°C to +85°C	CBT6832D DGG	SOT364-1

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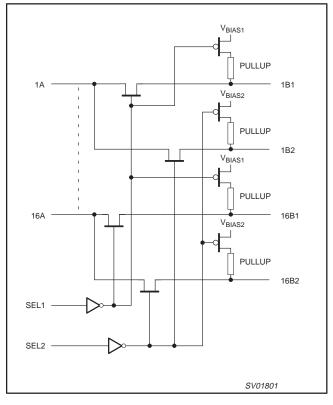
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
3, 6, 9, 12, 17, 20, 23, 26, 33, 36, 39, 42, 47, 50, 53, 56	1A1–16A1	Inputs
1, 2, 4, 5, 7, 8, 10, 11, 15, 16, 18, 19, 21, 22, 24, 25	1B1–16B1	Outputs
31, 32, 34, 35, 37, 38, 40, 41, 45, 46, 48, 49, 51, 52, 54, 55	1B2–16B2	Outputs
27, 30	V _{BIAS1} , V _{BIAS2}	Precharge bias voltage inputs
28, 29	SEL1, SEL2	Select-control inputs
13, 44	GND	Ground (0 V)
14, 43	V _{CC}	Positive supply voltage

FUNCTION TABLE

SEL1	SEL2	FUNCTION
L	Н	nA to nB1
Н	L	nA to nB2
L	L	nA to nB1 and nB2
Н	Н	nB1, nB2 = V _{BIAS}

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +7.0	V
I _{OUT}	DC output current	output in Low state	120	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Θ_{JA}	Power dissipation		95	°C/W

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C. 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL PARAMETEI	DADAMETED	LIM	ITS	UNIT
STWIDOL	FARAMETER	MIN	MAX	
V _{CC}	DC supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2.0		V
VIL	Low-level Input voltage		0.8	V
T _{amb}	Operating free-air temperature range	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

Over operating temperature range $T_{amb} = -40^{\circ}$ C to $+85^{\circ}$ C; $V_{CC} = 5 \text{ V} \pm 10\%$; $V_{BIAS} = 1.3 \text{ V}$ to V_{CC} , unless otherwise specified.

SYMBOL	DADAMETER	TEST CONDITIONS	LIMITS	LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	MIN	MIN TYP ¹ MAX	MAX	UNIT
V _{IH}	Input HIGH voltage	Guaranteed logic HIGH level	2.0			V
V _{IL}	Input LOW voltage	Guaranteed logic LOW level	-0.5		0.8	V
I _{IH}	Input HIGH current	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN} = V_{CC}$			±5	μA
Ι _{ΙL}	Input LOW current	V _{CC} = 5.5 V, V _{IN} = GND			±5	μΑ
I _{OZH}	High impedance output current				±1	μA
I _{OZL}	Low impedance output current		-0.2		-2	mA
V _{IK}	Input clamp voltage	$V_{CC} = 4.5 \text{ V}; \text{ I}_{\text{I}} = -18 \text{ mA}$		-0.7	-1.8	V
-	Switch on resistance ²	$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 48 \text{ mA}$		5	8	Ω
r _{on}	Switch on resistance=	$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 2.4 \text{ V}; \text{ I}_{I} = -15 \text{ mA}$		10	15	Ω
Capacitanc	:e³ (T _{amb} = +25°C; f = 1 MHz)					
C _{IN}	Input capacitance	$V_{I} = 0 V$		4.5		pF
C _{OFF B}	B capacitance, switch off	$V_{I} = 0 V$		8		pF
C _{OFF A}	A capacitance, switch off	$V_{I} = 0 V$		13		pF
C _{ON 1}	Capacitance, switch on (one B)	$V_{I} = 0 V$		21		pF
C _{ON 2}	Capacitance, both B channels enabled	$V_{I} = 0 V$		34		pF
Power sup	ply					
I _{CC}	Quiescent supply current enabled	V_{CC} = 5.5 V; V_{I} = V_{CC} or GND			200	μΑ
ΔI_{CC}	Additional supply current per input pin ⁵	V_{CC} = 5.5 V, one input at 3.4 V, other inputs at V _{CC} or GND			2.5	mA

NOTES:

All typical values are at V_{CC} = 5 V, T_{amb} = +25°C ambient and maximum loading.
 Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.

On-state resistance is determined by the lowest voltage of the two (A or B) terminals. These parameters are determined by device characterization, but is not production tested.

3.

4. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

 Per TTL driven input (V_I = 3.4 V, control inputs only); A and B pins do not contribute to I_{CC}.
 This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. this parameter is not tested, but is guaranteed by design.

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AC CHARACTERISTICS

 V_{CC} = 5.0 V ±0.5 V; GND = 0 V; C_L = 50 pF, R_L = 500 Ω

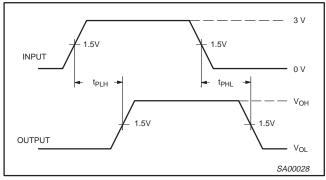
SYMBOL	SYMBOL PARAMETER TEST CONDITIONS	LIMITS			UNIT	
STMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	
t _{PLH} t _{PHL}	Propagation delay ¹ A to B			0.25		ns
t _{PZH} t _{PZL}	Bus enable time SEL to A, B		10 5		30 25	ns
t _{PHZ} t _{PLZ}	Bus disable time SEL to A, B		0.5 0.5		6 7	ns

NOTE:

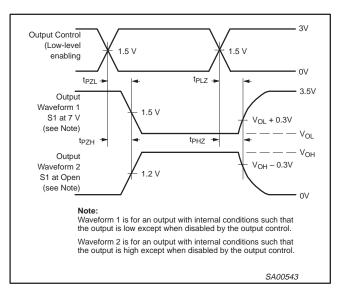
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

AC WAVEFORMS

 V_{M} = 1.5 V, V_{IN} = GND to 3.0 V

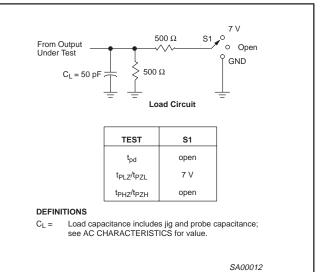


Waveform 1. Input (An) to Output (Bn) Propagation Delays

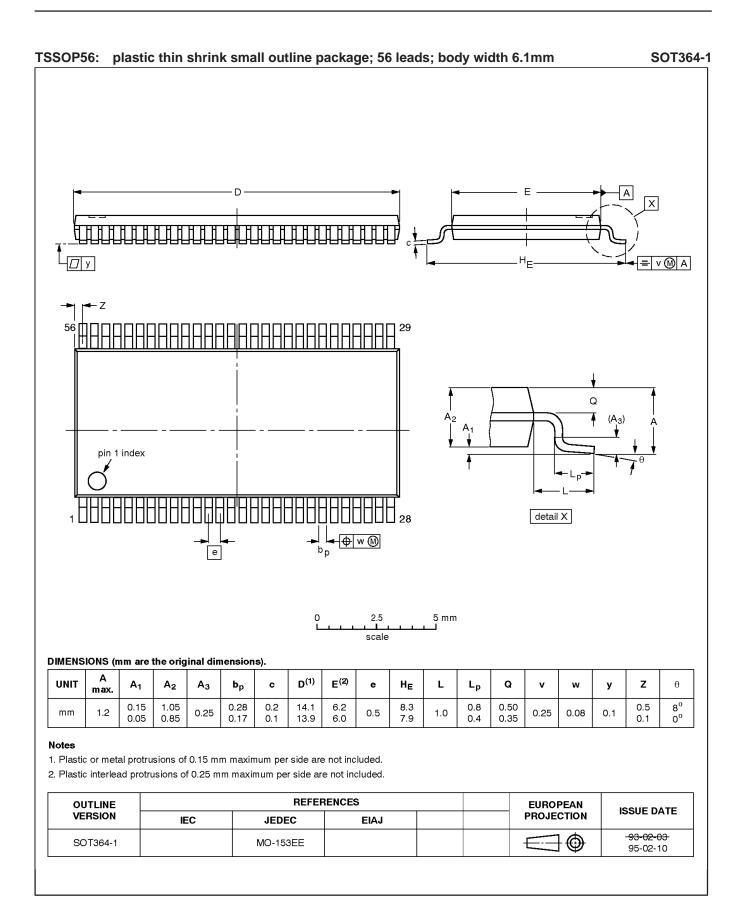


Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



CBT6832D



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NOTES

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Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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